180 W, DC - 2.0 GHz, 50 V, GaN HEMT

Description

Cree's CGHV40180F is an unmatched, gallium nitride (GaN) high electron mobility transistor (HEMT). The CGHV40180F, operating from a 50 volt rail, offers a general purpose, broadband solution to a variety of RF and microwave applications. GaN HEMTs offer high efficiency, high gain and wide bandwidth capabilities making the CGHV40180F ideal for linear and compressed amplifier circuits. The transistor is available in a 2-lead flange package.



Package Type: 440223 PN: CGHV40180F

Typical Performance Over 800 MHz - 1000 MHz ($T_c = 25$ °C), 50 V

Parameter	800 MHz	850 MHz	900 MHz	950 MHz	1000 MHz	Units
Small Signal Gain	25.6	25.2	24.9	24.4	24.3	dB
Gain @ P _{IN} 34 dBm	20.4	20.8	20.3	20.1	20.1	dB
Output Power @ P _{IN} 34 dBm	275	302	279	257	257	W
EFF @ P _{IN} 34 dBm	67	75	73	73	71	%

Note: Measured CW in the CGHV40180F-AMP Application circuit

Features

- Up to 2.0 GHz Operation
- 24 dB Small Signal Gain at 900 MHz
- 20 dB Power Gain at 900 MHz
- 250 W Typical Output Power at 900 MHz
- 75% Efficiency at P_{SAT}

Applications

- Military Communications
- Public Safety VHF-UHF applications
- Radar
- Medical
- Broadband Amplifiers





Absolute Maximum Ratings (not simultaneous) at 25 °C Case Temperature

Parameter	Symbol	Rating	Units	Conditions
Drain-Source Voltage	$V_{\scriptscriptstyle DSS}$	150	Volts	25°C
Gate-to-Source Voltage	V_{GS}	-10, +2	Volts	25°C
Storage Temperature	T _{STG}	-65, +150	°C	
Operating Junction Temperature ¹	T _J	225	°C	
Maximum Forward Gate Current	I _{GMAX}	42	mA	25°C
Maximum Drain Current ¹	I _{DMAX}	12.1	Α	25°C
Soldering Temperature ²	T_s	245	°C	
Screw Torque	τ	40	in-oz	
CGHV40180F Thermal Resistance, Junction to Case	$R_{_{\thetaJC}}$	0.95	°C/W	$P_{DISS} = 150, 85 ^{\circ} ^{\circ} ^{\circ}$
Maximum dissipated power		150	W	P _{DISS} = 150, 85 ° C
Case Operating Temperature ³	T _c	-40, +150	°C	

Notes:

Electrical Characteristics

Characteristics	Symbol	Min.	Тур.	Max.	Units	Conditions
DC Characteristics ¹ (T _c = 25 °C)						
Gate Threshold Voltage	$V_{\rm GS(th)}$	-3.8	-3.0	-2.3	V _{DC}	$V_{DS} = 10 \text{ V, I}_{D} = 41.8 \text{ mA}$
Gate Quiescent Voltage	$V_{GS(Q)}$	-	-2.7	-	V_{DC}	$V_{DS} = 50 \text{ V, } I_{D} = 1000 \text{ mA}$
Saturated Drain Current	I _{DS}	27.2	38.9	-	Α	$V_{DS} = 6.0 \text{ V}, V_{GS} = 2.0 \text{ V}$
Drain-Source Breakdown Voltage	V_{BR}	125	-	-	V _{DC}	$V_{GS} = -8 \text{ V, } I_{D} = 41.8 \text{ mA}$
RF Characteristics ² ($T_c = 25^{\circ}C$, $F_0 =$		less othe	rwise not	ed)		
Small Signal Gain	G _{ss}	23.4	24.0	_	dB	$V_{DD} = 50 \text{ V, } I_{DQ} = 1.0 \text{ A, } P_{in} = 10 \text{dBm CW}$
Power Gain	$G_{_{P}}$	19.3	20.3	-	dB	$V_{DD} = 50 \text{ V}, I_{DQ} = 1.0 \text{ A}, P_{in} = 34 \text{ dBm CW}$
Output Power	P _{out}	53.7	54.3	-	dBm	$V_{DD} = 50 \text{ V}, I_{DQ} = 1.0 \text{ A}, P_{in} = 34 \text{ dBm CW}$
Drain Efficiency ³	η	64	74	-	%	$V_{DD} = 50 \text{ V}, I_{DQ} = 1.0 \text{ A}, P_{in} = 34 \text{ dBm CW}$
Output Mismatch Stress	VSWR	_	-	3:1	Ψ	No damage at all phase angles, $V_{DD} = 50 \text{ V}$, $I_{DQ} = 1.0 \text{ A}$, $P_{OUT} = 180 \text{ W CW}$
Dynamic Characteristics						
Input Capacitance	C _{GS}	_	57.8	_	pF	$V_{DS} = 50 \text{ V}, V_{gs} = -8 \text{ V}, f = 1 \text{ MHz}$
Output Capacitance	C _{DS}	-	13.7	-	pF	$V_{DS} = 50 \text{ V}, V_{gs} = -8 \text{ V}, f = 1 \text{ MHz}$
Feedback Capacitance	C _{GD}	-	1.23	_	pF	$V_{DS} = 50 \text{ V}, V_{gs} = -8 \text{ V}, f = 1 \text{ MHz}$

Notes:

 $^{^{\}mbox{\tiny 1}}$ Current limit for long term, reliable operation

² Refer to the Application Note on soldering at <u>wolfspeed.com/rf/document-library</u>

³ See also, Power Derating Curve on Page 5

 $^{^{\}scriptscriptstyle 1}$ Measured on wafer prior to packaging

² Measurements are to be performed using Cree production test fixture AD-838292F-TB

 $^{^{3}}$ Drain Efficiency = P_{OUT}/P_{DC}

CGHV40180F Typical Performance

Figure 1. Small Signal Gain and Return Loss versus Frequency measured in application circuit CGHV40180F

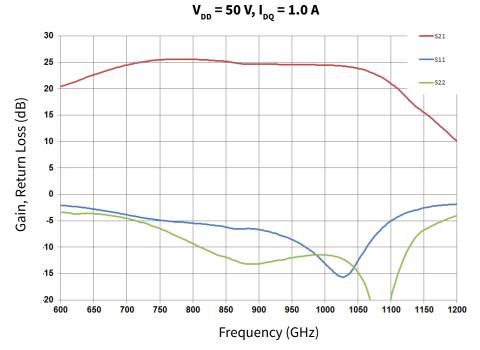
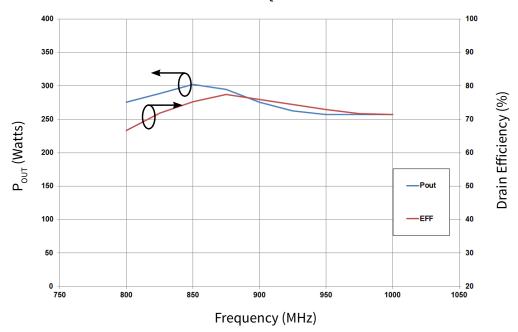


Figure 2. Output Power and Drain Efficiency vs Frequency CGHV40180F-TB CW Operation, $V_{\rm DD}$ = 50 V, $I_{\rm DQ}$ = 1.0 A, @ $P_{\rm IN}$ 34 dBm



CGHV40180F Typical Performance

Figure 3. Gain and Drain Efficiency vs. Frequency and Output Power CGHV40180F-TB CW Operation, $V_{\rm DD}$ = 50 V, $I_{\rm DQ}$ = 1.0A

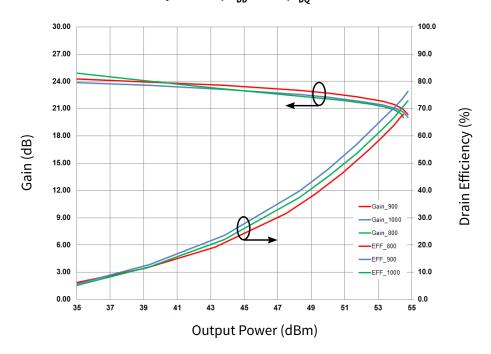
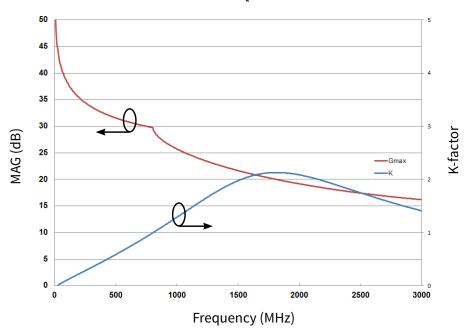


Figure 4. Simulated Maximum Available Gain and K-factor of the CGHV40180F V_{DD} = 50 V, I_{DQ} = 1.0 A



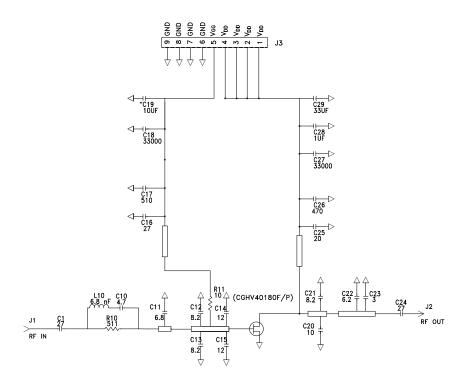
CGHV40180F Power Dissipation De-rating Curve

200.0 180.0 160.0 140.0 FLANGE Power Dissipation (W) 120.0 100.0 80.0 60.0 40.0 20.0 0.0 25 125 150 225 250

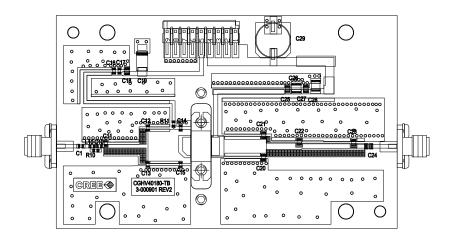
Maximum Case Temperature (°C)

Figure 5. Transient Power Dissipation De-rating Curve

CGHV40180F-AMP Application Circuit Schematic



CGHV40180F-AMP Application Circuit



CGHV40180F-AMP Application Circuit Bill of Materials

R11 RES, 1/16W, 0603, 1%, 10.0 OHMS 1 R10 RES, 1/16W, 0603, 1%, 511 OHMS 1 C29 CAP, 33UF, 20%, G CASE 1 C28 CAP 1.0UF, 100V, ±10%, X7R, 1210 1 C17 CAP, 510pF, NPO, 5%, 100V, 0603 1 C26 CAP, 470pF, NPO, 5%, 250V, ATC800B 1 C19 CAP, 10UF, 16V TANTALUM, 2312 1 C14, C15 CAP, 12.0pF, ±5%, 0603, ATC600S 2 C1, C16 CAP, 27pF, ±5%, 0603, ATC600S 2 C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1 C24 CAP, 27pF, ±5%, 250V, 0805, ATC600F 1
C29 CAP, 33UF, 20%, G CASE 1 C28 CAP 1.0UF, 100V, ±10%, X7R, 1210 1 C17 CAP, 510pF, NPO, 5%, 100V, 0603 1 C26 CAP, 470pF, NPO, 5%, 250V, ATC800B 1 C19 CAP, 10UF, 16V TANTALUM, 2312 1 C14, C15 CAP, 12.0pF, ±5%, 0603, ATC600S 2 C1, C16 CAP, 27pF, ±5%, 0603, ATC600S 2 C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1
C28 CAP 1.0UF, 100V, ±10%, X7R, 1210 1 C17 CAP, 510pF, NPO, 5%, 100V, 0603 1 C26 CAP, 470pF, NPO, 5%, 250V, ATC800B 1 C19 CAP, 10UF, 16V TANTALUM, 2312 1 C14, C15 CAP, 12.0pF, ±5%, 0603, ATC600S 2 C1, C16 CAP, 27pF, ±5%, 0603, ATC600S 2 C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1
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C19 CAP, 10UF, 16V TANTALUM, 2312 1 C14, C15 CAP, 12.0pF, ±5%, 0603, ATC600S 2 C1, C16 CAP, 27pF, ±5%, 0603, ATC600S 2 C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1
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C1, C16 CAP, 27pF, ±5%, 0603, ATC600S 2 C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1
C10 CAP, 4.7pF, ±0.1pF, 0603, ATC600S 1 C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1
C11 CAP, 6.8pF, ±0.25pF, 0603, ATC600S 1 C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1
C12, C13 CAP, 8.2pF, ±0.25 pF, 0603, ATC600S 2 C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1
C18, C27 CAP, 33000pF, 0805, 100V, X7R 2 C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1
C20 CAP, 10pF, ±1%, 250V, 0805, ATC600F 2 C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1
C25 CAP, 20pF, ±5%, 250V, 0805, ATC600F 1
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C24 CAP, 27pF, ±5%, 250V, 0805, ATC600F 1
C23 CAP, 3.0pF, ±0.1pF, 250V, 0805, ATC600F 2
C22 CAP, 6.2pF, ±0.1pF, 250V, 0805, ATC600F 1
C21 CAP, 8.2pF, ±0.1pF, 250V, 0805 ATC600F 1
- PCB ROGERS HTC6035, 0.020 THK, ER 3.60 1
J1,J2 CONN, SMA, PANEL MOUNT JACK, FLANGE, 4 HOLE BLUNT POST 2
J3 HEADER RT>PLZ .1CEN LK 9POS 1
L10 INDUCTOR, CHIP, 6.8nH, 5%, 0603 SMT, DIGIKEY 712-1432-1-ND 1
Q1 CGHV40180 1

CGHV40180F-AMP Demonstration Amplifier Circuit



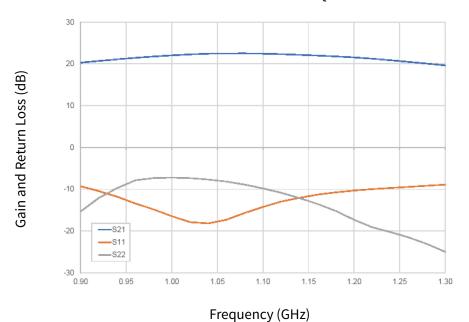
Electrical Characteristics When Tested in CGHV40180F-AMP3

Characteristics	Symbol	Min.	Тур.	Max.	Units	Conditions
RF Characteristics ¹ (T _c =	25°C, F ₀ =	0.96 - 1	.215 GH	z unless	otherw	ise noted)
Small Signal Gain	G _{ss}	-	> 20	_	dB	$V_{DD} = 50 \text{ V}, I_{DQ} = 1.0 \text{ A}$
Power Gain	$G_{_{P}}$	-	> 16	-	dBm	$V_{_{DD}}$ = 50 V, $I_{_{DQ}}$ = 1.0 A, $P_{_{IN}}$ = 38 dBm, 128 μ s, 10% pulse
Output Power	P _{out}	-	250	-	W	$V_{_{DD}}$ = 50 V, $I_{_{DQ}}$ = 1.0 A, $P_{_{IN}}$ = 38 dBm, 128 μ s, 10% pulse
Drain Efficiency	η	-	> 75	_	%	V_{DD} = 50 V, I_{DQ} = 1.0 A, P_{IN} = 38 dBm, 128 μ s, 10% pulse
Output Mismatch Stress	VSWR	_	3:1	-	Ψ	No damage at all phase angles, V_{DD} = 50 V, I_{DQ} = 1.0 A, P_{IN} = 38 dBm, 128 μ s, 10% pulse

CGHV40180F

Typical Performance in Application Circuit CGHV40180F-AMP3

Figure 5. Small Signal Gain and Return Losses of the CGHV40180F Measured in Demonstration Amplifier Circuit CGHV40180F-AMP3 CW Operation, $V_{DD} = 50 \text{ V}$, $I_{DO} = 1.0 \text{ A}$



¹Measured in CGHV40180F-AMP3 Application Circuit

CGHV40180F-AMP3 Application Circuit Schematic

Figure 6. Pulsed Output Power and Drain Efficiency vs. Frequency of the CGHV40180F-AMP3 V_{DD} = 50 V, I_{DQ} = 1.0 A, P_{IN} = 38 dBm, 128 μ s, 10% pulse

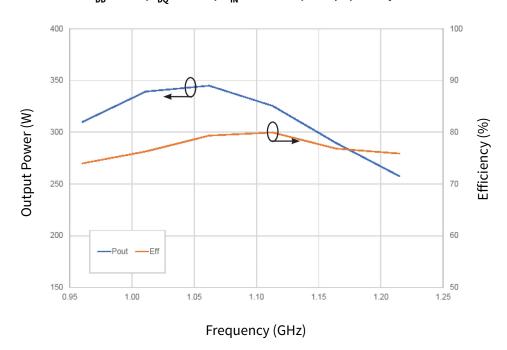
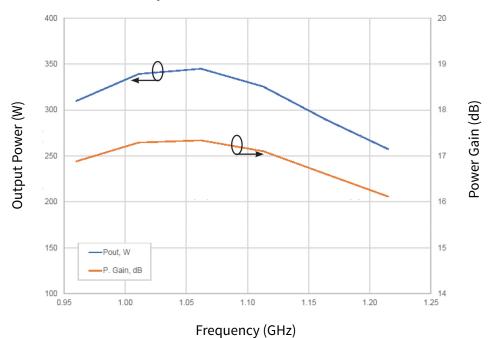


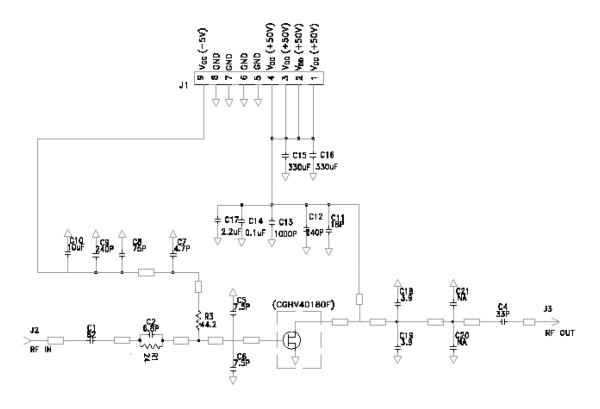
Figure 7. Output Power and Power Gain vs. Frequency of the CGHV40180F-AMP3 V $_{_{DD}}$ = 50 V, I $_{_{DQ}}$ = 1.0 A, P $_{_{IN}}$ = 38 dBm, 128 μs , 10% pulse



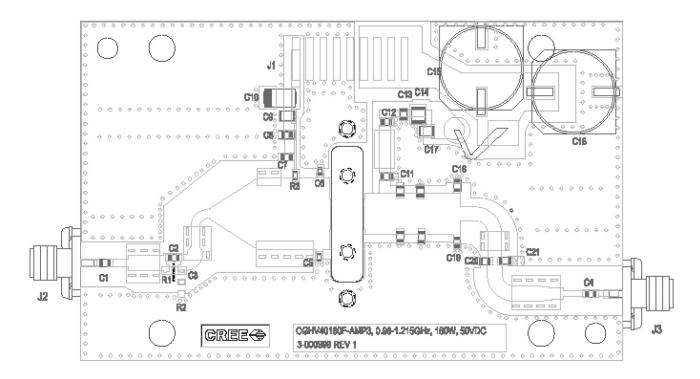
Rev 1.6 - April 2020

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CGHV40180F-AMP3 Application Circuit Schematic



CGHV40180F-AMP3 Application Circuit



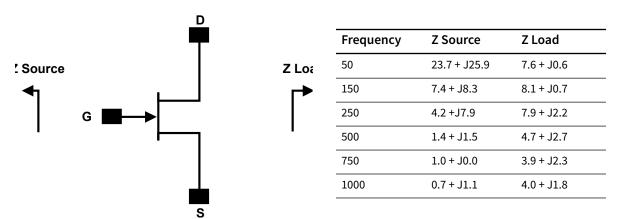
CGHV40180F-AMP3 Bill of Materials

C2 CAP, 8.2pF, +/-0.1pF, 250V, 0805, ATC600F 1 C1 CAP, 82pF, 1%, 250V, 0805, ATC600F 1 C5, C6 CAP,7.5PF, 1%, 0603, ATC600S 2 C9, C12 CAP, 240pF, 5%, 250V, 0805, ATC600F 1 C7 CAP, 4.7pF, +/-0.1pF, 250V, 0603, ATC600S 1 C8 CAP, 75pF, 5%, 250V, 0805, ATC600F 1 C11 CAP, 18pF, 1%, 250V, 0805, ATC600F 1 C13 CAP, 1000P, 5%, 250V, 0603 1 C14 CAP, 0.1uF, 5%, 250V, 0805 1 C17 CAP, 2.2uF, 5%, 100V, 1210 1 C15, C16 CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3 2 C18, C19 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 2 C4 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R2 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	Designator	Description	Qty
C5, C6 CAP,7.5PF, 1%, 0603, ATC600S 2 C9, C12 CAP, 240PF, 5%, 250V, 0805, ATC600F 1 C7 CAP, 4.7PF, +/-0.1PF, 250V, 0603, ATC600S 1 C8 CAP, 75PF, 5%, 250V, 0805, ATC600F 1 C11 CAP, 18PF, 1%, 250V, 0805, ATC600F 1 C13 CAP, 1000P, 5%, 250V, 0603 1 C14 CAP, 0.1uF, 5%, 250V, 0805 1 C17 CAP, 2.2uF, 5%, 100V, 1210 1 C15, C16 CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3 2 C18, C19 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 2 C4 CAP, 33pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES, 1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C2	CAP, 8.2pF, +/-0.1pF, 250V, 0805, ATC600F	1
C9, C12 CAP, 240pF, 5%, 250V, 0805, ATC600F C7 CAP, 4.7pF, +/-0.1pF, 250V, 0603, ATC600S 1 C8 CAP, 75pF, 5%, 250V, 0805, ATC600F 1 C11 CAP, 18pF, 1%, 250V, 0805, ATC600F 1 C13 CAP, 1000P, 5%, 250V, 0603 1 C14 CAP, 0.1uF, 5%, 250V, 0805 1 C17 CAP, 2.2uF, 5%, 100V, 1210 1 C15, C16 CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3 2 C18, C19 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 2 C4 CAP, 33pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 31pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 UNI WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C1	CAP, 82pF, 1%, 250V, 0805, ATC600F	1
C7 CAP, 4.7pF, +/-0.1pF, 250V, 0603, ATC600S 1 C8 CAP, 75pF, 5%, 250V, 0805, ATC600F 1 C11 CAP, 18pF, 1%, 250V, 0805, ATC600F 1 C13 CAP, 1000P, 5%, 250V, 0603 1 C14 CAP, 0.1uF, 5%, 250V, 0805 1 C17 CAP, 2.2uF, 5%, 100V, 1210 1 C15, C16 CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3 2 C18, C19 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 2 C4 CAP, 33pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C5, C6	CAP,7.5PF, 1%, 0603, ATC600S	2
C8 CAP, 75pF, 5%, 250V, 0805, ATC600F 1 C11 CAP, 18pF, 1%, 250V, 0805, ATC600F 1 C13 CAP, 1000P, 5%, 250V, 0603 1 C14 CAP, 0.1uF, 5%, 250V, 0805 1 C17 CAP, 2.2uF, 5%, 100V, 1210 1 C15, C16 CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3 2 C18, C19 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 2 C4 CAP, 33pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C9, C12	CAP, 240pF, 5%, 250V, 0805, ATC600F	1
C11 CAP, 18pF, 1%, 250V, 0805, ATC600F 1 C13 CAP, 1000P, 5%, 250V, 0603 1 C14 CAP, 0.1uF, 5%, 250V, 0805 1 C17 CAP, 2.2uF, 5%, 100V, 1210 1 C15, C16 CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3 2 C18, C19 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 2 C4 CAP, 33pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	С7	CAP, 4.7pF, +/-0.1pF, 250V, 0603, ATC600S	1
C13 CAP, 1000P, 5%, 250V, 0603 1 C14 CAP, 0.1uF, 5%, 250V, 0805 1 C17 CAP, 2.2uF, 5%, 100V, 1210 1 C15, C16 CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3 2 C18, C19 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 2 C4 CAP, 33pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C8	CAP, 75pF, 5%, 250V, 0805, ATC600F	1
C14 CAP, 0.1uF, 5%, 250V, 0805 1 C17 CAP, 2.2uF, 5%, 100V, 1210 1 C15, C16 CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3 2 C18, C19 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 2 C4 CAP, 33pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C11	CAP, 18pF, 1%, 250V, 0805, ATC600F	1
C17 CAP, 2.2uF, 5%, 100V, 1210 1 C15, C16 CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3 2 C18, C19 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 2 C4 CAP, 33pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C13	CAP, 1000P, 5%, 250V, 0603	1
C15, C16 CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3 2 C18, C19 CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F 2 C4 CAP, 33pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C14	CAP, 0.1uF, 5%, 250V, 0805	1
C18, C19	C17	CAP, 2.2uF, 5%, 100V, 1210	1
C4 CAP, 33pF, 5%, 250V, 0805, ATC600F 1 C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C15, C16	CAP, 330 UF, 20%, 100V, ELEC, Vishay, MAL215099911E3	2
C10 CAP, 10uF, 16V, TANTLUM 2 R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C18, C19	CAP, 3.9pF, +/-0.1pF, 250V, 0805, ATC600F	2
R1 RES, 24 OHM IMS, 1005 1 R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C4	CAP, 33pF, 5%, 250V, 0805, ATC600F	1
R3 RES,1/16W,0603,1%,44.2 OHMS 1 W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	C10	CAP, 10uF, 16V, TANTLUM	2
W1 WIRE, 18G, BALCK, 2.5" 1 J2, J3 CONN, SMA, PANEL MOUNT JACK, FL 2 J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	R1	RES, 24 OHM IMS, 1005	1
J2, J3CONN, SMA, PANEL MOUNT JACK, FL2J1HEADER ST, .1CEN LK 9POS, PBC05SABN1	R3	RES,1/16W,0603,1%,44.2 OHMS	1
J1 HEADER ST, .1CEN LK 9POS, PBC05SABN 1	W1	WIRE, 18G, BALCK, 2.5"	1
,	J2, J3	CONN, SMA, PANEL MOUNT JACK, FL	2
- BASEPLATE. 1	J1	HEADER ST, .1CEN LK 9POS, PBC05SABN	1
2,102,12,12,	-	BASEPLATE,	1
PCB, RO4350B, 2.5"x4"x0.020", 1	-	PCB, RO4350B, 2.5"x4"x0.020",	1
- #2, WASHER, SPLIT LK, SS 4	-	#2, WASHER, SPLIT LK, SS	4
- 2-56 SOC HD SCREW 3/16 SS 4	_	2-56 SOC HD SCREW 3/16 SS	4
Q1 CGHV40180F 1	Q1	CGHV40180F	1

CGHV40180F-AMP3 Demonstration Amplifier Circuit



Source and Load Impedances



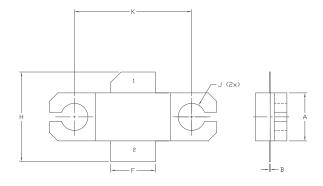
Note 1. V_{DD} = 50 V, I_{DQ} = 1.0A in the 440223 package Note 2. Optimized for Power Gain, P_{SAT} and Drain Efficiency

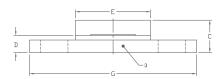
Note 3. When using this device at low frequency, series resistor should be used to maintain amplifier stability

Electrostatic Discharge (ESD) Classifications

Parameter	Symbol	Class	Test Methodology
Human Body Model	НВМ	1A (> 250 V)	JEDEC JESD22 A114-D
Charge Device Model	CDM	2 (125 V to 250 V)	JEDEC JESD22 C101-C

Product Dimensions CGHV40180F (Package Type — 440223)





1. DIMENSIONING AND TOLERANICING PER ANSI Y14.5M, 1982.

3. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF 0.020° BEYOND EDGE OF LID.

4. LID MAY BE MISALIGNED TO THE BODY OF THE PACKAGE BY A MAXIMUM OF 0.008' IN ANY DIRECTION. 5. ALL PLATED SURFACES ARE NI/AU

	INC	HES	MILLIN	IETERS			
DIM	MIN	MAX	MIN	MAX			
Α	0.225	0.235	5.72	5.97			
В	0.004	0.006	0.10	0.15			
С	0.145	0.165	3.68	4.19			
D	0.077	0.087	1.96	2.21			
E	0.355	0.365	9.02	9.27			
F	0.210	0.220	5.33	5.59			
G	0.795	0.805	20.19	20.45			
Н	0.400	0.460	10.16	11.68			
J	ø.	130	3.3	30			
k	0.5	62	14.	27			

Part Number System

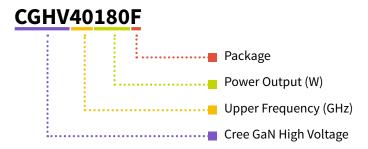


Table 1.

Parameter	Value	Units
Upper Frequency ¹	4.0	GHz
Power Output	100	W
Package	Flange	-

Note¹: Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

Table 2.

Character Code	Code Value
A	0
В	1
С	2
D	3
E	4
F	5
G	6
Н	7
J	8
K	9
Examples:	1A = 10.0 GHz 2H = 27.0 GHz

Product Ordering Information

Order Number	Description	Unit of Measure	Image
CGHV40180F	GaN HEMT	Each	Call to St.
CGHV40180F-AMP3	Test board with GaN HEMT (flanged) installed	Each	

For more information, please contact:

4600 Silicon Drive Durham, North Carolina, USA 27703 www.wolfspeed.com/RF

Sales Contact RFSales@cree.com

Notes

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